

TG 438-S

Visible and UV laser diodes in TO56 package



Features:

Optical output power: 50mW (Tcase=20°C)

Peak wavelength: 438 +/- 2 nm @RT

Efficient radiation source for cw and pulsed operation

Single transverse mode semiconductor laser

Absolute maximum ratings

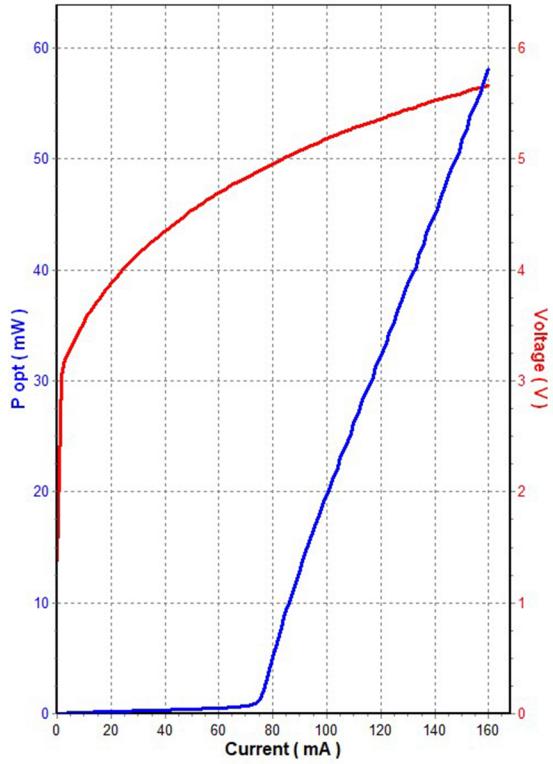
Item	Symbol	Absolute Maximum Ratings	Unit
Allowable Reverse Current	I _r	1	[uA]
PD Reverse Voltage	V _r	5	[V]
Storage Temperature	T _{storage}	-10~85	[°C]
Operating Case Temperature	T _C	0~60 [*]	[°C]

Electric/Optical Characteristics

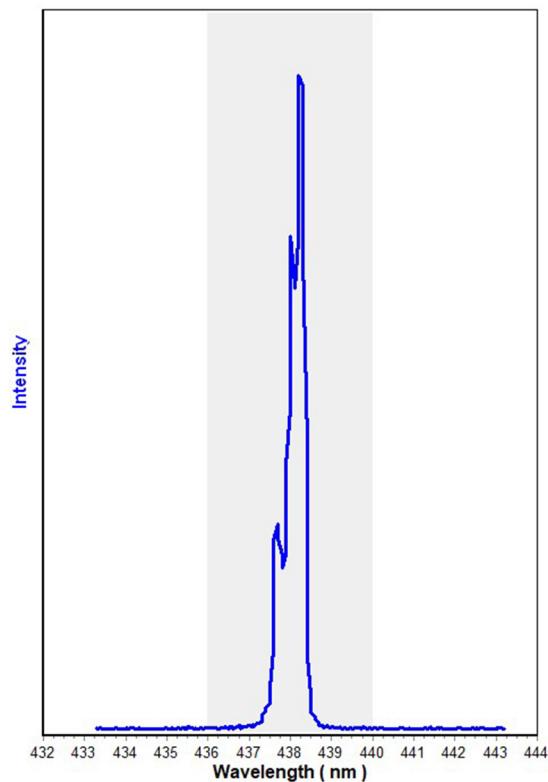
Item	Condition	Symbol	Value	Unit
Optical Output Power	CW	P _O	50	[mW]
Peak Wavelength	P _O =50mW	λ _p	438 +/- 2	[nm]
Threshold Current	CW	I _{th}	64-112	[mA]
Operating Current	P _O =50mW	I _{op}	137-180	[mA]
Temperature wavelength shift	P _O =50mW	DI	0.05	[nm/deg]
Beam divergence - Fast axis			32	deg
Beam divergence - Slow axis			7	deg

*Please notice that the laser diode is designed to operate at room temperature (20 deg. C). The temperature increase leads to the shorter lifetime and lower output current.

Optical output power

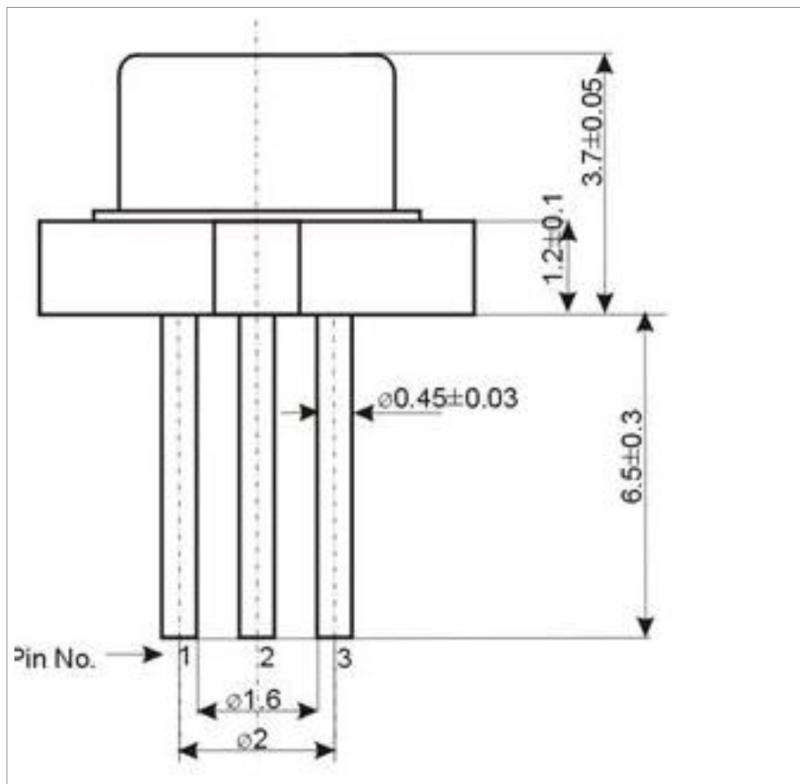


Wavelength



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Physical dimentions



Electrical connections

Laser is connected to isolated pins “1” and “3”. Pin “2” is connected with the case and not active.

